

SGM4553YXET

2-Bit Bidirectional Voltage-Level Translator for Open-Drain and Push-Pull Applications

GENERAL DESCRIPTION

SGM4553YXET is a 2-bit, non-inverting. bidirectional voltage-level translator which features two independent configurable power-supply lines. The A and B ports track the V_{CCA} supply and V_{CCB} supply respectively. The supply voltage range is 1.65V to 5.5V for A ports and 2.3V to 5.5V for B ports. The device provides a bidirectional translation function among the different voltage nodes (including 1.8V, 2.5V, 3.3V and 5V).

The SGM4553YXET has an output enable (OE) function, which controls the inputs and outputs states. When OE goes low, all I/Os enter high-impedance state. It is beneficial for reducing quiescent current consumption. When V_{CCA} is powered, OE has an internal pull-down current source.

SGM4553YXET is available XTDFN-1.35×1-8L package. It operates over an ambient temperature range of -40°C to +85°C.

FEATURES

- Power Supply Voltage Ranges (V_{CCA} ≤ V_{CCB})
 - A Ports: 1.65V to 5.5V
 - + B Ports: 2.3V to 5.5V
- Direction-Control Signal is Not Required
- Data Rates
 - Push-Pull: 24Mbps
 - Open-Drain: 2Mbps
- Support V_{CCA} or V_{CCB} Isolation
 - When V_{CCA} or V_{CCB} is Low, Device Enters **Power-Down Mode**
- No Specific Power Sequences Required for V_{CCA} and V_{CCB}
- Support Power-Down Mode
- -40°C to +85°C Operating Temperature Range
- Available in a Green XTDFN-1.35×1-8L Package

APPLICATIONS

Universal Asynchronous Receiver/Transmitter I²C/SMBus Interfaces General Purpose I/O (GPIO)

TYPICAL APPLICATION

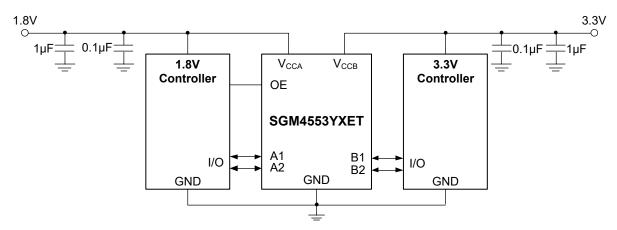
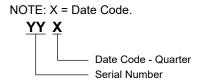


Figure 1. Typical Application Circuit

PACKAGE/ORDERING INFORMATION

MODEL	PACKAGE DESCRIPTION	SPECIFIED TEMPERATURE RANGE	ORDERING NUMBER	PACKAGE MARKING	PACKING OPTION	
SGM4553YXET	XTDFN-1.35×1-8L	-40°C to +85°C	SGM4553YXET8G/TR	2TX	Tape and Reel, 5000	

MARKING INFORMATION



Green (RoHS & HSF): SG Micro Corp defines "Green" to mean Pb-Free (RoHS compatible) and free of halogen substances. If you have additional comments or questions, please contact your SGMICRO representative directly.

ABSOLUTE MAXIMUM RATINGS

Supply Voltage Range	
V _{CCA}	0.3V to 6V
V _{CCB}	0.3V to 6V
Input Voltage Range, V _I ⁽¹⁾	
A Ports, B Ports, OE	0.3V to 6V
Output Voltage Range for the High-Impeda	ance or Power-Off
State, V _O ⁽¹⁾	
A Ports	0.3V to 6V
B Ports	0.3V to 6V
Output Voltage Range for the High or Low S	State, V _O ^{(1) (2)}
A Ports0.3	
B Ports0.3	3V to V_{CCB} + 0.3V
Input Clamp Current, I _{IK} (V _I < 0)	50mA
Output Clamp Current, I _{OK} (V _O < 0)	50mA
Continuous Output Current, Io	±50mA
Continuous Current through V_{CCA} , V_{CCB} , or	GND±100mA
Package Thermal Resistance	
XTDFN-1.35×1-8L, θ _{JA}	276°C/W
Junction Temperature	+150°C
Storage Temperature Range	65°C to +150°C
Lead Temperature (Soldering, 10s)	+260°C
ESD Susceptibility	
HBM	4000V
MM	300V
CDM	1000V

NOTES:

- 1. When the input and output current ratings are observed, the input and I/O negative voltage ratings may be exceeded.
- 2. V_{CCA} and V_{CCB} values are shown in the recommended operating conditions in Electrical Characteristics section.

RECOMMENDED OPERATING CONDITIONS

Operating Temperature Range-40°C to +85°C

OVERSTRESS CAUTION

Stresses beyond those listed in Absolute Maximum Ratings may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect reliability. Functional operation of the device at any conditions beyond those indicated in the Recommended Operating Conditions section is not implied.

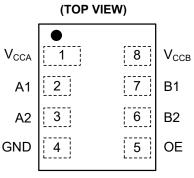
ESD SENSITIVITY CAUTION

This integrated circuit can be damaged if ESD protections are not considered carefully. SGMICRO recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage. ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because even small parametric changes could cause the device not to meet the published specifications.

DISCLAIMER

SG Micro Corp reserves the right to make any change in circuit design, or specifications without prior notice.

PIN CONFIGURATION



XTDFN-1.35×1-8L

PIN DESCRIPTION

PIN	NAME	FUNCTION
1	V _{CCA}	Supply Voltage on A Port. It can be operated from 1.65V to 5.5V, and V _{CCA} is always ≤ V _{CCB} .
2	A1	Channel 1 Input/Output A. It tracks the V _{CCA} supply.
3	A2	Channel 2 Input/Output A. It tracks the V _{CCA} supply.
4	GND	Ground.
5	OE	Output Enable Control Pin. Active high. When OE goes low, all outputs enter into the high-impedance state. It tracks the V_{CCA} supply.
6	B2	Channel 2 Input/Output B. It tracks the V _{CCB} supply.
7	B1	Channel 1 Input/Output B. It tracks the V _{CCB} supply.
8	V _{CCB}	Supply Voltage on B Port. It can be operated from 2.3V to 5.5V.

ELECTRICAL CHARACTERISTICS

 $(V_{CCA} = 1.65V \text{ to } 5.5V, V_{CCB} = 2.3V \text{ to } 5.5V, T_A = -40^{\circ}\text{C}$ to +85°C, typical values are at $T_A = +25^{\circ}\text{C}$, unless otherwise noted.)

PARAMETER		SYMBOL	CON	IDITIONS	MIN	TYP	MAX	UNITS		
Recommended Ope	erating Condition	ons ^{(1) (2)}	•				<u> </u>			
		V_{CCA}			1.65		5.5			
Supply Voltage (3)		V _{CCB}			2.3		5.5	V		
	A D-# 1/O-		$V_{CCA} = 1.65V \text{ to } 1.9$	95V, V _{CCB} = 2.3V to 5.5V	V _{CCI} - 0.2		V _{CCI}			
High-Level Input	A Port I/Os	V _{IH}	V _{CCA} = 2.3V to 5.5V	V _{CCI} - 0.4		V _{CCI}	V			
Voltage	B Port I/Os				V _{CCI} - 0.4		V _{CCI}	V		
	OE Input				V _{CCA} × 0.8		5.5			
	A Port I/Os				0		0.15			
Low-Level Input Voltage	B Port I/Os	V_{IL}			0		0.15	5 V		
renage	OE Input				0		V _{CCA} × 0.25	:5		
			A port I/Os push-pu	ull driving			10			
Input Transition Rise or Fall Rate		Δt/ΔV	B port I/Os push-po	ull driving			10	ns/V		
			Control input				10			
Electrical Character	ristics									
A Ports High Level O	output Voltage	V_{OHA}	$I_{OH} = -20\mu A, V_{IB} \ge V_{CCB} - 0.4V$		V _{CCA} × 0.7					
A Ports Low Level O	utput Voltage	V_{OLA}	I _{OL} = 1mA, V _{IB} ≤ 0.15V				0.4	V		
B Ports High Level C	output Voltage	V_{OHB}	$I_{OH} = -20\mu A, V_{IA} \ge V$	V _{CCA} - 0.4V	V _{CCB} × 0.7			V		
B Ports Low Level O	utput Voltage	V_{OLB}	$I_{OL} = 1 \text{mA}, V_{IA} \le 0.7$	15V			0.4			
Input Leakage	OE	_	T _A = +25°C				±1	^		
Current	OE	l ₁	$T_A = -40^{\circ}C \text{ to } +85^{\circ}$	С			±1.5	μA		
	A Ports		V _{CCA} = 0V,	T _A = +25°C			±0.5			
Power-Off Leakage	AFOILS		$V_{CCB} = 0V \text{ to } 5.5V$	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$			±1	μА		
Current	B Ports	- I _{OFF}	$V_{CCA} = 0V \text{ to } 5.5V,$	T _A = +25°C			±0.5			
			V _{CCB} = 0V	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$			±1			
3-State Output	A or B Ports	loz	OE = 0V	T _A = +25°C			±0.6			
Leakage	AUIDFUIS	l _{oz}	OE - 0V	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$			±1	μA		

NOTES:

- 1. V_{CCI} is the supply voltage associated with the input ports.
- 2. $\ensuremath{V_{\text{CCO}}}$ is the supply voltage associated with the output ports.
- 3. Ensure that $V_{CCA} \le V_{CCB}$ and V_{CCA} must not exceed 5.5V.

ELECTRICAL CHARACTERISTICS (continued)

 $(V_{CCA} = 1.65V \text{ to } 5.5V, V_{CCB} = 2.3V \text{ to } 5.5V, T_A = -40^{\circ}\text{C}$ to +85°C, typical values are at $T_A = +25^{\circ}\text{C}$, unless otherwise noted.)

PARAME	TER	SYMBOL	CON	IDITIONS	MIN	TYP	MAX	UNITS	
			V _I = V _O = OPEN,	$V_{CCA} = 1.65V \text{ to } V_{CCB},$ $V_{CCB} = 2.3V \text{ to } 5.5V$			5.5		
		I _{CCA}	$I_0 = 0A$	V _{CCA} = 5.5V, V _{CCB} = 0V			5.5	μA	
				V _{CCA} = 0V, V _{CCB} = 5.5V			-1		
			$V_1 = V_0 = OPEN$,	$V_{CCA} = 1.65V \text{ to } V_{CCB},$ $V_{CCB} = 2.3V \text{ to } 5.5V$			15		
Quiescent Supply Current	000	$I_0 = 0A$	V _{CCA} = 5.5V, V _{CCB} = 0V			-1	μΑ		
ж				V _{CCA} = 0V, V _{CCB} = 5.5V			6		
		I _{CCA} + I _{CCB}	$V_1 = V_0 = OPEN,$ $I_0 = 0A$	$V_{CCA} = 1.65V \text{ to } V_{CCB}, \ V_{CCB} = 2.3V \text{ to } 5.5V$			20	μΑ	
		I _{CCZA}	,	V _{CCA} = 1.65V to V _{CCB} , V _{CCB} = 2.3V to 5.5V			5.5	μΑ	
		I _{CCZB}	,	$V_{CCA} = 1.65V \text{ to } V_{CCB},$ $V_{CCB} = 2.3V \text{ to } 5.5V$			5.5	μΑ	
OE Input Capacitance C ₁		Cı	V _{CCA} = 3.3V, V _{CCB} = 3.3V			4		pF	
Input/Output	A Ports					5			
Capacitance	B Ports	C _{IO}	$V_{CCA} = 3.3V, V_{CCB} =$	- 3.3V		5		pF	

TIMING REQUIREMENTS

 $(T_A = +25^{\circ}C, \text{ unless otherwise noted.})$

DADAMETED	OVMDOL	CONDITIONS	V _{CCB} = 2.5V	V _{CCB} = 3.3V	V _{CCB} = 5V	LINUTO	
PARAMETER	SYMBOL	CONDITIONS	TYP	TYP	TYP	UNITS	
(V _{CCA} = 1.8V)	•					•	
Data Data		Push-pull driving	21	22	24	N Alama	
Data Rate		Open-drain driving	2	2	2	Mbps	
Pulse Duration	4	Push-pull driving	47	45	41		
(Data Inputs)	t _W	Open-drain driving	500	500	500	ns	
(V _{CCA} = 2.5V)	•		<u>.</u>				
Data Data		Push-pull driving	20	22	24	N 41	
Data Rate		Open-drain driving	2	2	2	Mbps	
Pulse Duration		Push-pull driving	50	45	41	ns	
(Data Inputs)	t _W	Open-drain driving	500	500	500		
(V _{CCA} = 3.3V)	•		<u>.</u>				
Data Data		Push-pull driving		23	24	N Alexe e	
Data Rate		Open-drain driving		2	2	Mbps	
Pulse Duration		Push-pull driving		43	41		
(Data Inputs)	t _W	Open-drain driving		500	500	ns	
(V _{CCA} = 5V)	•	1	•	1			
D . D .		Push-pull driving			24		
Data Rate		Open-drain driving			2	Mbps	
Pulse Duration		Push-pull driving			41		
(Data Inputs)	t _W	Open-drain driving			500	ns	

SWITCHING CHARACTERISTICS

($V_{CCA} = 1.8V$, $T_A = +25$ °C, unless otherwise noted.)

DADAMETER	OVANDOL	0.0	NUDITIONS	V _{CCB} = 2.5V	V _{CCB} = 3.3V	V _{CCB} = 5V	LINUTO	
PARAMETER	SYMBOL		ONDITIONS	TYP	TYP	TYP	UNITS	
			Push-pull driving	2.4	3.0	4.3		
	t _{PHL}	A 4 - D	Open-drain driving	26.0	26.3	26.7		
		A to B	Push-pull driving	4.0	3.6	3.5	ns	
Decreasion Dalay	t _{PLH}		Open-drain driving	175	145	110		
Propagation Delay			Push-pull driving	2.0	1.9	2.1		
	t _{PHL}	D to A	Open-drain driving	26.0	26.1	26.2		
		B to A	Push-pull driving	1.7	1.5	1.4	ns	
	t _{PLH}		Open-drain driving	133	69	51		
Enable Time	t _{EN} (t _{PZH} & t _{PZL})	OE to A or B		24	20	18	ns	
Disable Time	t _{DIS} (t _{PHZ} & t _{PLZ})	OE to A or B		1200	1200	1200	ns	
		A Ports	Push-pull driving	6.6	5.8	5.4	ns	
Dia a Tima	t _{rA}	APORS	Open-drain driving	89	31	10		
Rise Time		B Ports	Push-pull driving	5.6	4.6	3.9	ns	
	t _{rB}		Open-drain driving	128	98	58		
		4.5.	Push-pull driving	2.9	2.7	2.6		
Fall Times	t _{fA}	A Ports	Open-drain driving	1.9	1.7	1.6	ns	
Fall Time		D.Dt-	Push-pull driving	4.6	5.9	8.0		
	t _{fB}	B Ports	Open-drain driving	2.2	2.3	2.9	ns	
Channel-to-Channel Skew	t _{sko}			0.5	0.5	0.5	ns	
Data Rate		Push-pull drivi	ng	21	22	24	Mhna	
Dala Nale		Open-drain driving		2	2	2	Mbps	

SWITCHING CHARACTERISTICS (continued)

($V_{CCA} = 2.5V$, $T_A = +25$ °C, unless otherwise noted.)

DADAMETED	OVALDOL	00	NUDITIONS	V _{CCB} = 2.5V	V _{CCB} = 3.3V	V _{CCB} = 5V	шито	
PARAMETER	SYMBOL	CO	NDITIONS	TYP	TYP	TYP	UNITS	
			Push-pull driving	2.7	3.3	4.8		
	t _{PHL}	A to B	Open-drain driving	26.2	26.4	26.7		
		AIOD	Push-pull driving	2.6	2.4	2.3	ns	
Dranagation Daloy	t _{PLH}		Open-drain driving	169	144	110		
Propagation Delay	_		Push-pull driving	2.4	2.3	2.4		
	t _{PHL}	D. t. A	Open-drain driving	26.3	26.4	26.5		
		B to A	Push-pull driving	2.0	1.9	1.8	ns	
	t _{PLH}		Open-drain driving	pen-drain driving 165		55		
Enable Time	t _{EN} (t _{PZH} & t _{PZL})	OE to A or B		23	19	16	ns	
Disable Time	t _{DIS} (t _{PHZ} & t _{PLZ})	OE to A or B		1200	1200	1200	ns	
		A Ports	Push-pull driving	3.2	2.8	2.6		
Dia a Tima	t _{rA}		Open-drain driving	120	70	10	ns	
Rise Time			Push-pull driving	4.5	3.4	2.6		
	t _{rB}	B Ports	Open-drain driving	122	96	62	ns	
		A Doub	Push-pull driving	4.9	5.0	4.8		
Fall Time	t _{fA}	A Ports	Open-drain driving	2.0	1.9	1.7	ns	
Fall Time		D.Dd-	Push-pull driving	4.8	6.1	8.3		
	t_{fB}	B Ports	Open-drain driving	1.9	2.1	2.7	ns	
Channel-to-Channel Skew	t _{sko}		•	0.5	0.5	0.5	ns	
Data Rate		Push-pull drivi	ng	20	22	24	Mhns	
Data Rate		Open-drain dri	Open-drain driving		2	2	Mbps	

SWITCHING CHARACTERISTICS (continued)

($V_{CCA} = 3.3V$, $T_A = +25$ °C, unless otherwise noted.)

DAD AMETED	OVALDOL	CONDITIONS		V _{CCB} = 3.3V	V _{CCB} = 5V		
PARAMETER	SYMBOL		CONDITIONS	TYP	TYP	UNITS	
			Push-pull driving	3.5	4.9		
	t _{PHL}	A to B	Open-drain driving	26.3	26.7	Ī	
	_	AIOB	Push-pull driving	2.2	2.0	ns	
Dranagation Daloy	t _{PLH}		Open-drain driving	133	104		
Propagation Delay	4		Push-pull driving	3.0	3.2		
	t _{PHL}	D 45 A	Open-drain driving	26.6	26.8		
		B to A	Push-pull driving	1.8	1.7	ns	
	t _{PLH}		Open-drain driving	132	83		
Enable Time	t _{EN} (t _{PZH} & t _{PZL})	OE to A or B		18	15	ns	
Disable Time	t _{DIS} (t _{PHZ} & t _{PLZ})	OE to A or B		1200	1200	ns	
		A Donto	Push-pull driving	2.2	2.0		
Dies Times	t_{rA}	A Ports	Open-drain driving	87	36	ns	
Rise Time		D Davida	Push-pull driving	2.9	2.3		
	t_{rB}	B Ports	Open-drain driving	87	56	ns	
		A Donto	Push-pull driving	6.2	5.8		
Fall Time	t _{fA}	A Ports	Open-drain driving	2.3	2.0	ns	
Fall Time	,	D.D. etc.	Push-pull driving	6.5	8.2		
	t_{fB}	B Ports	Open-drain driving	2.0	2.5	ns	
Channel-to-Channel Skew	t _{sko}			0.5	0.5	ns	
Data Rate		Push-pull driv	ing	23	24	Mhns	
Data Kate		Open-drain driving		2	2	Mbps	

SWITCHING CHARACTERISTICS (continued)

($V_{CCA} = 5V$, $T_A = +25$ °C, unless otherwise noted.)

DADAMETED	OVALDOL		COMPITIONS	V _{CCB} = 5V		
PARAMETER	SYMBOL		CONDITIONS	TYP	UNITS	
			Push-pull driving	5.4		
	t _{PHL}	A 4 - D	Open-drain driving	26.7		
		A to B	Push-pull driving	1.9	ns	
Dranagation Daloy	t _{PLH}		Open-drain driving	120		
Propagation Delay			Push-pull driving	5.6		
	t _{PHL}	D to A	Open-drain driving	27.3		
		B to A	Push-pull driving	1.7	ns	
	t _{PLH}		Open-drain driving	126		
Enable Time	t _{EN} (t _{PZH} & t _{PZL})	OE to A or B		16	ns	
Disable Time	t _{DIS} (t _{PHZ} & t _{PLZ})	OE to A or B		1200	ns	
		A Ports	Push-pull driving	1.8		
Dia a Tima	t _{rA}	A Ports	Open-drain driving	79	ns	
Rise Time		D. Dorto	Push-pull driving	2.2	no	
	t_{rB}	B Ports	Open-drain driving	73	ns	
		A Davida	Push-pull driving	8.7		
Fall Times	t _{fA}	A Ports	Open-drain driving	2.7	ns	
Fall Time	_	D. Danta	Push-pull driving	8.6		
	t_{fB}	B Ports	Open-drain driving	2.4	ns	
Channel-to-Channel Skew	t _{sko}			0.5	ns	
Data Rate		Push-pull drivi	ng	24	Mbps	
Data Nate		Open-drain dr	iving	2	Ivibha	

WAVEFORMS

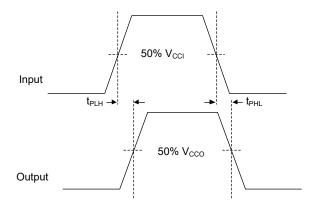


Figure 2. Propagation Delay

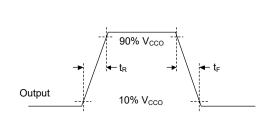


Figure 4. Rise Time and Fall Time of Data Output

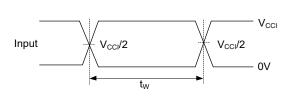
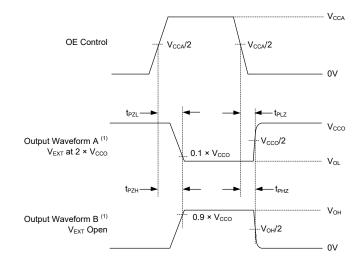


Figure 3. Pulse Duration

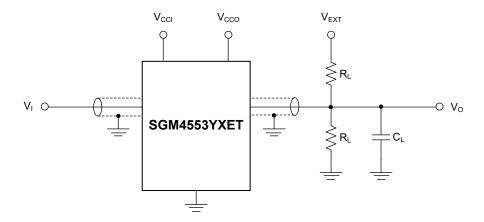


NOTE:

1. Waveform A indicates an output that is high except for OE is high. Waveform B indicates an output that is low except for OE is high.

Figure 5. Enable and Disable Times

TEST CIRCUIT



Definitions for test circuit:

R_L = Load resistance.

C_L = Load capacitance includes jig and probe capacitance.

 V_{EXT} = External voltage for measuring switching times.

 V_{CCI} = Supply voltage associated with the input.

 V_{CCO} = Supply voltage associated with the output.

Figure 6. Test Circuit for Measuring Switching Times

APPLICATION INFORMATION

Applications

The SGM4553YXET is a bridge between two digital systems with different power supplies as it can transmit the signal transparently. For the application of the SGM4553YXET, the output driver is open-drain or push-pull to drive the I²C or one-wire bus. In addition, if a device with push-pull driver is connected to the I/O pin of the SGM4553YXET, it will operate as normal.

Architecture

The SGM4553YXET can switch the direction of the transmission for port A and port B automatically without any external control.

There is no need to add an external direction control for the application of the SGM4553YXET. Also, each I/O pin can be an input or output of the voltage translator.

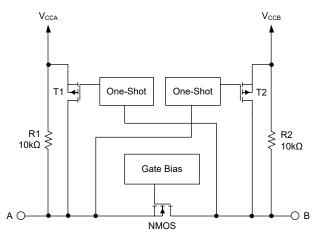


Figure 7. Architecture of an SGM4553YXET Cell

The explanation of two main parts of the internal circuit for the SGM4553YXET is shown as below:

- There is an NMOS between port A and port B to switch on or off the transmission.
- The one-shot accelerator can be used to accelerate the rising edges of the signal for port A and port B automatically.

Input Driver Requirements

The falling time of port A and port B and t_{PHL} depend on the output impedance of the connected device. The values of parameters which are t_{fA} , t_{fB} , t_{PHL} and data rates are specified when the resistance of external driver is less than 500.

Power-Up

For the application of the SGM4553YXET, the V_{CCA} should be less than V_{CCB} . However, it does not matter if the power supply voltage is ramping, and the sequence of power-up for both V_{CCA} and V_{CCB} is not defined.

Output Load Considerations

To decrease the extend of capacitive loading and ensure the proper triggering of O.S., the trace in PCB should be as short as possible. Also, to ensure that the round-trip reflection delay is smaller than the time period of one-shot, the users should also decrease the length of trace, which means that the signal integrity is guaranteed because of the low impedance for the reflection. The period of on-state for the O.S. part is 30ns. In addition, for the one-shot circuit, it can support lumped capacitive load. In addition, the one-shot circuit has the time-out function, which aims to handle the extremely heavy capacitive load. For the function of O.S. part of the SGM4553YXET, it can optimize the trade-off between the capability of load driving, maximum bit-rate and dynamic supply current. The length of PCB trace and output connectors will be considered as the capacitive load of the device, which may result in the retriggering of O.S., contention of bus and the oscillations of the output.

Enable and Disable

The function of OE is used to disable SGM4553YXET by setting the transmitting I/O pins to high-impedance mode. The pull-down current source is integrated inside OE once it is powered by V_{CCA} . The definition of disable time (t_{DIS}) is the time period between OE goes low and when all of the I/O pins are in high-impedance mode. The enable time (t_{EN}) is defined as the time period between OE goes to high position and one-shot part starts to operate.

Pull-Up or Pull-Down Resistors on I/O Lines

For the I/O pin of A and B side, there is a $10k\Omega$ pull-up resistor to provide a high position for each I/O pin. However, if a smaller pull-up resistor is required, the users can add an external resistor which is parallel with the $10k\Omega$ resistor. Also, the value of V_{OL} can be affected by the added external resistor. In addition, if the user wants to disable the device, the OE pin can be simply set to low position.

SGM4553YXET

2-Bit Bidirectional Voltage-Level Translator for Open-Drain and Push-Pull Applications

REVISION HISTORY

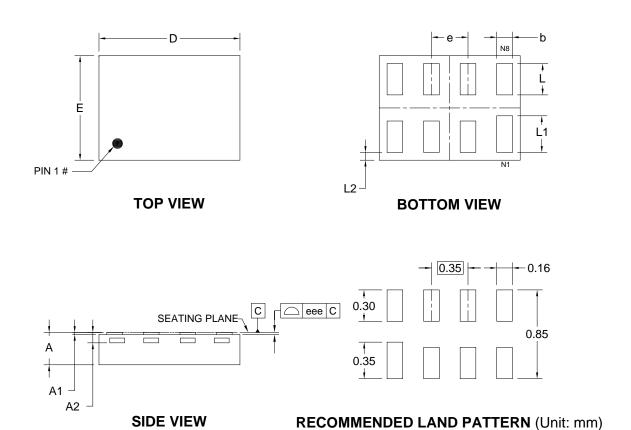
NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Original (OCTOBER 2023) to REV.A

Page



PACKAGE OUTLINE DIMENSIONS XTDFN-1.35×1-8L



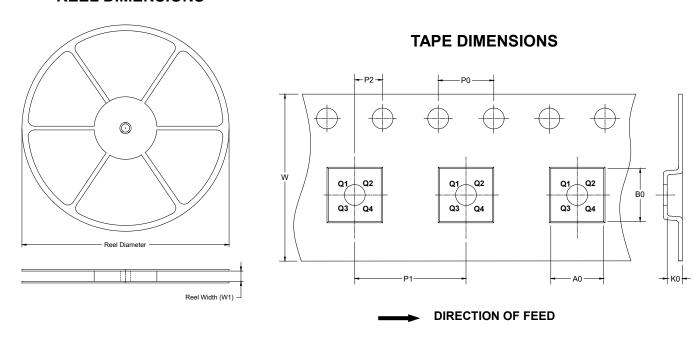
Symbol	Dii	mensions In Millimet	ers					
Symbol	MIN	MOD	MAX					
Α	-	0.310	0.330					
A1	0.000	-	0.050					
A2		0.100 REF						
D	1.250	1.350	1.450					
E	0.900	1.000	1.100					
b	0.110	0.160	0.210					
е		0.350 BSC						
L	0.250	0.300	0.350					
L1	0.300	0.400						
L2	0.075 REF							
eee	-	0.050	-					

NOTE: This drawing is subject to change without notice.



TAPE AND REEL INFORMATION

REEL DIMENSIONS

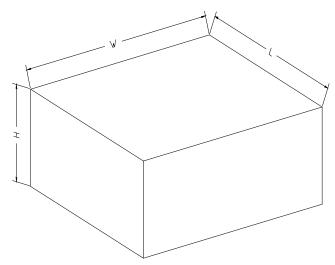


NOTE: The picture is only for reference. Please make the object as the standard.

KEY PARAMETER LIST OF TAPE AND REEL

Package Type	Reel Diameter	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P0 (mm)	P1 (mm)	P2 (mm)	W (mm)	Pin1 Quadrant
XTDFN-1.35×1-8L	7"	9.5	1.21	1.51	0.39	4.0	4.0	2.0	8.0	Q1

CARTON BOX DIMENSIONS



NOTE: The picture is only for reference. Please make the object as the standard.

KEY PARAMETER LIST OF CARTON BOX

Reel Type	Length (mm)	Width (mm)	Height (mm)	Pizza/Carton
7" (Option)	368	227	224	8
7"	442	410	224	18